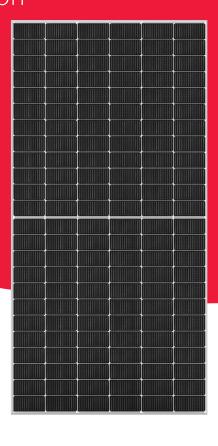
NB-JD570

570 W The Project Solution

Bifacial

N-Type TOPCon



Powerful product features

- Max. system voltage 1,500 V Lower BOS costs by longer strings
- Module efficiency 22.07 %
 N-Type TOPCon monocrystalline silicon
 photovoltaic modules
- **+%** Guaranteed positive power tolerance (0/+5 %)
- MBB busbar technology
 Improved reliability
 Higher efficiency
 Reduced series resistance
- Half-cut cell
 Improved shading performance
 Lower internal losses
- Bifacial module

 Additional rear side power gain

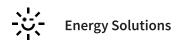
- Tested and certified

 VDE, IEC/EN61215, IEC/EN61730

 Safety class II, CE
- Safety class II, CE
 Fire rating class A
 - PID resistance test passed
 Salt mist test passed (IEC61701)
 Ammonia test passed (IEC62716)
 Dust and sand test passed (IEC60068)

Your solar partner for life

- **60** years of solar expertise
 - Local support team in Europe
- Linear power output guarantee
- 50 million PV modules installed
- **15*** Product guarantee
- Tier 1 BloombergNEF





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Electrical data (STC, NMOT)				
		NB-JD570 (STC)	NB-JD570 (NMOT)	
Maximum power	P _{max}	570	425.63	Wp
Open-circuit voltage	Voc	52.13	48.75	V
Short-circuit current	Isc	13.91	11.23	А
Voltage at point of maximum power	V _{mpp}	42.8	39.89	V
Current at point of maximum power	Impp	13.32	10.67	А
Module efficiency	ηm	22.07		%
Bifaciality factor		80 ±5		%

 $STC = Standard \ Test \ Conditions: irradiance \ 1,000 \ W/m^2, AM \ 1.5, cell \ temperature \ 25 \ ^{\circ}C. \ Rated \ electrical \ characteristics \ are \ within \ \pm 10 \ \% \ of \ the \ indicated \ values \ of \ I_{SC}, V_{OC} \ and \ 0 \ to \ +5 \ \% \ of \ P_{max}. \ Reduction \ of \ efficiency \ from \ an \ irradiance \ change \ of \ 1,000 \ W/m^2 \ to \ 200 \ W/m^2 \ is \ less \ than \ 3 \ \%. \ NMOT = Nominal \ Module \ Operating \ Temperature: \ 45 \ ^{\circ}C, \ irradiance \ 800 \ W/m^2, \ air \ temperature \ of \ 20 \ ^{\circ}C, \ wind \ speed \ of \ 1 \ m/s.$

Bifacial Generation Data (STC)							
				NB-JD570			
Power gain rear side		5	10	15	20	25	%
Maximum power	P _{max}	598.77	627.02	655.69	683.94	712.62	Wp
Open-circuit voltage	Voc	52.13	52.13	52.13	52.13	52.13	V
Short-circuit current	I _{sc}	14.61	15.30	16.00	16.69	17.39	А
Voltage at point of maximum power	V_{mpp}	42.80	42.80	42.80	42.80	42.80	V
Current at point of maximum power	Impp	13.99	14.65	15.32	15.98	16.65	А

Mechanical data	
Length	2,278 mm
Width	1,134 mm
Depth	30 mm
Weight	32.5 kg

Temperature coefficient		
P _{max}	-0.300 %/°C	
Voc	-0.248 %/°C	
I _{sc}	0.047 %/°C	

Limit values	
Maximum system voltage	1,500 V DC
Over-current protection	30 A
Temperature range	-40 to 85 °C
Max. mechanical load (snow/wind)	2,400 Pa
Tested snow load	5,400 Pa

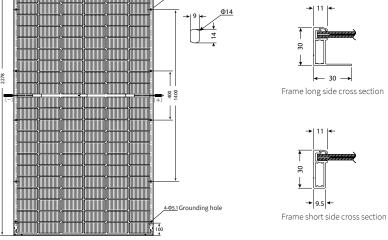
Packaging data** Modules per pallet Pallet size 2.31 m×1.12 m×1.21 m $(L \times W \times H)$ Approx. 1.210 kg Pallet weight

**Special offloading requirements, please refer to QR code or: www.sharp.eu/NBJD-offloading

(IEC61215 test pass*)



Module rear side view



^{*}Please refer to SHARP's installation manual for details

General data	
Cells	Half-cut cell mono, 182 mm x 91 mm, MBB, 2 strings of 72 cells in series
Front glass	Anti-reflective high transmissive low iron tempered glass, 2 mm
Rear glass	Tempered glass, 2 mm
Frame	Anodized aluminium alloy, silver
Cable	ø 4.0 mm², length (+) 400 mm, (-) 200 mm
Connection box	IP68 rating, 3 bypass diodes
Connector	C1, IP68

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